

FEB 22 2005

AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s): Fengyan Zhang, Wei-Wei Zhuang, and Sheng Teng Hsu			Docket No. SLA0642		
Serial No 10/784,669	Filing Date February 23, 2004	Examiner	Group Art Unit 2812		
Invention: Buffer Layers to Enhance the C-Axis Growth of Bi4Ti3O12 Thin Film on High Temperature Iridium Composite Electrode					
TO THE COMMISSIONER FOR PATENTS:					
Transmitted herewith is an amendment in the above identified application. The fee has been calculated and is transmitted as shown below.					
CLAIMS AS AMENDED					
	CLAIMS REMAINING AFTER AMENDMENT	HIGHEST # PREV. PAID FOR	NUMBER OF EXTRA CLAIMS PRESENT	RATE	ADDITIONAL FEE
TOTAL CLAIMS	16 -	20 =	0	x \$50.00	\$0.00
INDEP. CLAIMS	2 -	3 =	0	x \$200.00	\$0.00
Multiple Dependent Claims (check if applicable) _____					\$0.00
TOTAL ADDITIONAL FEE FOR THIS AMENDMENT					\$0.00

☒ No additional fee is required for amendment.

☐ Please charge Deposit Account No. 19-1457 in the amount of \$0.00.

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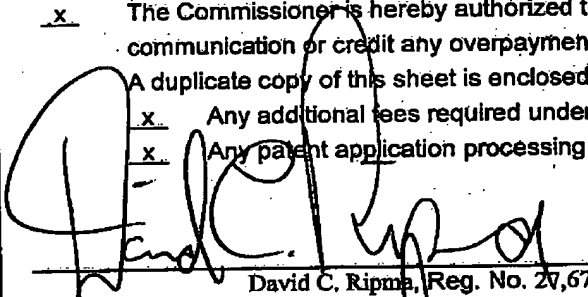
☒ The Commissioner is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account No. 19-1457.

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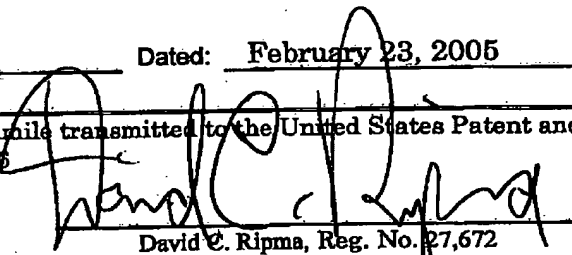
☒ Any additional fees required under 37 C.F.R. 1.16.

☒ Any patent application processing fees under 37 C.F.R. 1.17.

Dated: February 23, 2005


 David C. Ripma, Reg. No. 27,672

I hereby certify that this correspondence is being facsimile transmitted to the United States Patent and Trademark Office under 37 C.F.R. §1.8 at Fax No. (703) 872-9306 on February 23, 2005.


 David C. Ripma, Reg. No. 27,672

Note: Each paper must have its own certificate of transmission, or this certificate must identify each submitted paper. The papers submitted include:

<input checked="" type="checkbox"/> This Amendment Transmittal Letter (Include Duplicate)	2 page(s)
<input checked="" type="checkbox"/> Response under 37 CFR § 1.111	6 page(s)
<input type="checkbox"/> Attachments	0 page(s)
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Serial No.: 10/784,669
Applicant: Fengyan Zhang *et al.*
Filed: February 23, 2004
Group #: 2818
Examiner: David Nhu

Confirmation Number: 2291

Docket No: SLA.0642
Customer No: 27518
For: Buffer Layers to Enhance the C-axis growth of $\text{Bi}_4\text{Ti}_3\text{O}_{12}$ Thin Film on a High Temperature Iridium Composite Electrode

MS AMENDMENT
Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

RESPONSE TO OFFICE ACTION UNDER 37 C.F.R. § 1.111
Introductory Comments

In response to the Office Action dated January 5, 2005, please amend the above-identified Application as follows:

Amendment to the Specification None

Amendment to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Amendment to the Drawings None

Remarks/Arguments begin on page 6 of this paper.

An Appendix is not included.

Page 1 Response to Office Action under 37 C.F.R. § 1.111 for Serial No. 10/784,669

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